

	U	I	Inventor	Document	Issn	P	Title	Current	Current X	Retrieval	S	C	P	Y	Image	Doc	P
1			Calafut, Da	US 622818	2001	9	Very high aspect ratio semiconductor	257/24	257/392		P	C	P	P		US 622818	
2			Rostoker, M	US 5777360	1998	19	Hexagonal field programmable gate ar	257/31	257/401		P	C	P	P		US 577736	
3			Lidow, Alex	US 5742067	1998	13	High power MOSFET with low on-resista	257/34	257/339		P	C	P	P		US 574208	
4			Tokura, Nor	US 6015787	2000	2	Production method of a vertical type M	438/27	257/1214		P	C	P	P		US 601573	
5			Rostoker, M	US 5681581	19970	17	Microelectronic integrated circuit incl	328/10	257/206		P	C	P	P		US 568158	
6			Bulucea, G	US 662795	2003	4	Trench DMOS power transistor with fiel	257/32	257/330		P	C	P	P		US 662795	
7			Okabe, Yos	US 6608378	2003	37	Vertical type MOSFET	257/33	257/331		P	C	P	P		US 660837	
8			Blanchard, US	6046473	2000	15	Structure and process for reducing the	257/34	257/342		P	C	P	P		US 604647	
9			Ayala, Chris	US 595558	1999	11	Current limiting circuit with continuou	438/20	257/328		P	C	P	P		US 595555	
10			Bulucea, G	US 589735	1999	2	Method of manufacturing insulated ga	438/27	257/1292		P	C	P	P		US 589735	